

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
1	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C = 25°C	110	Α
D	Pulsed Drain Current	T _C = 25°C	See Figure4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	968	mJ
р	Power Dissipation		333	W
PD	Derate above 25°C		2.22	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.45	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB9403	FDB9403_F085	TO-263AB	330mm	24mm	800 units

Notes:

1. Current is limited by bondwire configuration. Please see Fairchild AN 9757-1 for details on test method. 2. Starting $T_J = 25^{\circ}C$, L = 0.47mH, $I_{AS} = 64A$, $V_{DD} = 40V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche. 3. $R_{\theta,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Symbol	Parameter	Test Condition	s Min	Тур	Max	Units
Off Cha	racteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	40	-	-	V
	Drain to Source Leakage Current	V_{DS} =40V, T_{J} = 25°C	-	-	1	μA
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V$ $T_{J} = 175^{\circ}$	C(Note 4) -	-	1	mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA
r _{DS(on)}	Drain to Source On Resistance	$I_{\rm D} = 80A, \qquad T_{\rm J} = 25^{\circ}C$		1.0	1.2	mΩ
r _{DS(on)}	Drain to Source On Resistance		- C(Note 4) -	1.0	1.2 1.96	mΩ mΩ
	c Characteristics			1		
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V,	-	12700	-	pF
C _{oss}	Output Capacitance	-f = 1MHz	-	3195	-	pF
C _{rss}	Reverse Transfer Capacitance		-	493	-	pF
R _g	Gate Resistance	f = 1MHz	-	2.9	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V_{GS} = 0 to 10V V_{DI}	_ = 20V	164	213	nC
Q _{g(th)}	Threshold Gate Charge		- A08	23	30	nC

Switching Characteristics

Gate to Source Gate Charge

Gate to Drain "Miller" Charge

t _{on}	Turn-On Time		-	-	56	ns
t _{d(on)}	Turn-On Delay Time		-	16	-	ns
t _r	Rise Time	V _{DD} = 20V, I _D = 80A,	-	19.5	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{DD} = 20V, I _D = 80A, V _{GS} = 10V, R _{GS} = 1.5Ω	-	61	-	ns
t _f	Fall Time		-	46	-	ns
t _{off}	Turn-Off Time		-	-	171	ns

-

-

59

25

-

-

nC

nC

Drain-Source Diode Characteristics

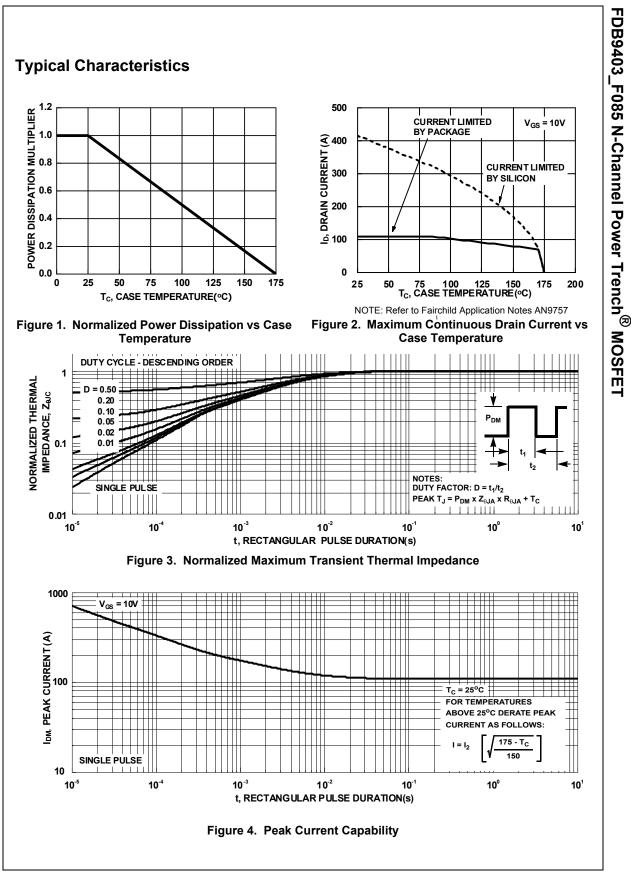
V	Courses to Drain Diado Maltona	I _{SD} = 35A, V _{GS} = 0V	-	-	0.85	V
V_{SD}	Source to Drain Diode Voltage	I _{SD} = 15A, V _{GS} = 0V	-	-	0.80	V
T _{rr}	Reverse Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs	-	96	125	ns
Q _{rr}	Reverse Recovery Charge	$F = 00A$, $displat = 100A/\mu s$	-	149	194	nC

Notes:

 Q_gs

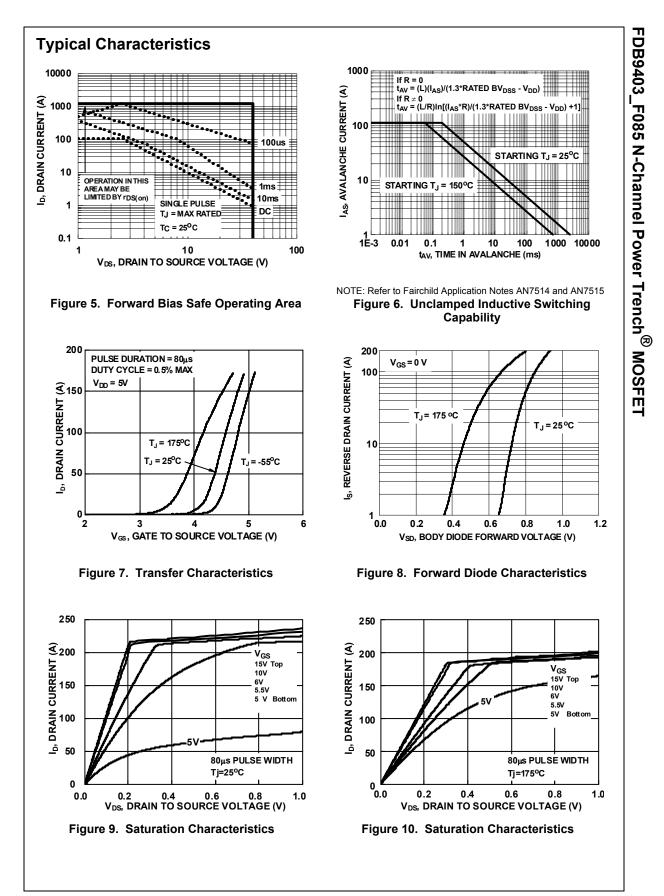
Q_{gd}

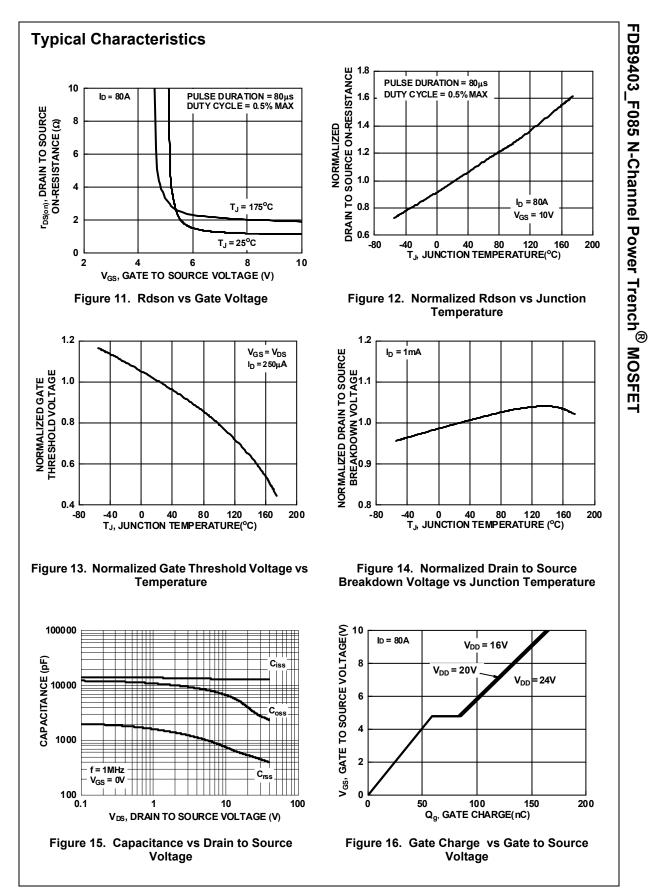
4: The maximum value is specified by design at TJ = 175°C. Product is not tested to this condition in production.



FDB9403_F085 Rev. C1

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